



30V P-CHANNEL ENHANCEMENT MODE MOSFET POWERDI®

Product Summary

V _{(BR)DSS}	R _{DS(ON)} max	I _D max T _A = +25°C		
001/	10mΩ @ V _{GS} = -10V	-11.5A		
-30V	18mΩ @ V _{GS} = -4.5V	-8.7A		

Description

This MOSFET has been designed to minimize the on-state resistance (R_{DS(ON)}) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- Backlighting
- **Power Management Functions**
- DC-DC Converters

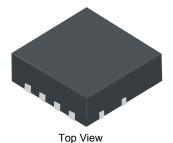
Features and Benefits

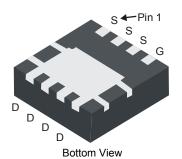
- Low R_{DS(ON)} ensures on state losses are minimized
- Small form factor thermally efficient package enables higher density end products
- Occupies just 33% of the board area occupied by SO-8 enabling smaller end product
- **ESD Protected Gate**
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

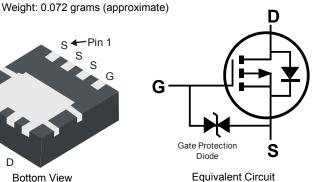
Mechanical Data

- Case: POWERDI3333-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See diagram Terminals: Finish – Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208 @3









Ordering Information (Note 4)

Part Number	Case	Packaging
DMP3017SFG-7	POWERDI3333-8	2,000/Tape & Reel
DMP3017SFG-13	POWERDI3333-8	3,000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



P17= Product Type Marking Code YYWW = Date Code Marking YY = Last digit of year (ex: 13 = 2013) WW = Week code $(01 \sim 53)$



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Units
Drain-Source Voltage			V _{DSS}	-30	V
Gate-Source Voltage			V _{GSS}	±25	V
Continuous Prais Current (Note 6) // = 10/	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I _D	-11.5 -9.4	А
Continuous Drain Current (Note 6) V _{GS} = -10V	t<10s	T _A = +25°C T _A = +70°C	I _D	-15.2 -12.1	А
Maximum Continuous Body Diode Forward Current (Note 5)			I _S	-3.0	Α
Pulsed Drain Current (10µs pulse, duty cycle = 1%)			I _{DM}	-80	Α
Avalanche Current (Notes 7) L = 1mH			I _{AR}	14	Α
Repetitive Avalanche Energy (Notes 7) L = 1mH			E _{AR}	104	mJ

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

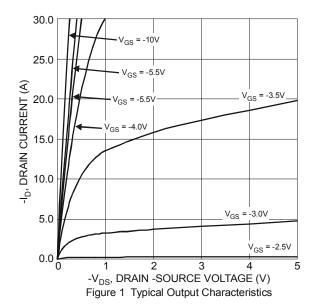
Characteristic	Symbol	Value	Units		
Total Power Dissipation (Note 5)	T _A = +25°C	Б	0.94	W	
Total Fower Dissipation (Note 5)	T _A = +70°C	P_D	0.6		
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	В	137	°C/W	
Thermal Resistance, Junction to Ambient (Note 5)	t < 10s	$R_{ heta JA}$	82	°C/W	
Total Dayor Dissination (Note 6)	T _A = +25°C	Б	2.2	- W	
Total Power Dissipation (Note 6)	T _A = +70°C	P_{D}	1.3		
Thermal Desigtance Junction to Ambient (Note C)	Steady State	Б	60	°C/W	
Thermal Resistance, Junction to Ambient (Note 6)	t < 10s	R ₀ JA	36	°C/W	
Thermal Resistance, Junction to Case (Note 6)	$R_{ heta JC}$	3.0	°C/W		
Operating and Storage Temperature Range	T _{J,} T _{STG}	-55 to +150	°C		

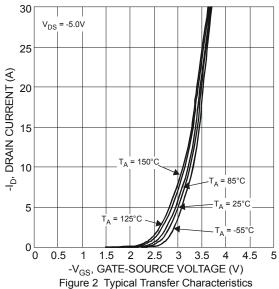


Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

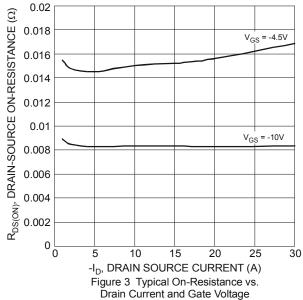
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BV _{DSS}	-30	_	_	V	$V_{GS} = 0V, I_D = -250\mu A$	
Zero Gate Voltage Drain Current	I _{DSS}		_	-1	μA	V _{DS} = -24V, V _{GS} = 0V	
Gate-Source Leakage	I _{GSS}	_	_	±10	μA	$V_{GS} = \pm 25V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V _{GS(th)}	-1.0	_	-3.0	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	
Static Drain-Source On-Resistance			8.5	10	mΩ	$V_{GS} = -10V, I_D = -11.5A$	
Static Dialii-Source Off-Resistance	R _{DS (ON)}	_	15	18	11122	$V_{GS} = -4.5V$, $I_D = -8.5A$	
Forward Transfer Admittance	Y _{fs}	_	24	_	S	$V_{DS} = -5V, I_{D} = -11.5A$	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	C _{iss}	1	2246	_	pF	1, 45, 1, 0, 0, 0	
Output Capacitance	Coss	1	352	_	pF	V_{DS} = -15V, V_{GS} = 0V, -f = 1.0MHz	
Reverse Transfer Capacitance	C _{rss}	_	294	_	pF	1.514112	
Gate resistance	R_g	1	5.1	12	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge (V _{GS} = 5V)	Qg		20.5	_	nC		
Total Gate Charge (V _{GS} = 10V)	Qg	_	41	_	nC	\\\ - 45\\ \ \ - 44.5\	
Gate-Source Charge	Q _{gs}	_	7.6	_	nC	$V_{DS} = -15V, I_D = -11.5A$	
Gate-Drain Charge	Q _{gd}	_	8.0	_	nC		
Turn-On Delay Time	t _{D(on)}	_	7.5	_	ns	$V_{DD} = -15V$, $V_{GS} = -10V$, $R_G = 6\Omega$, $I_D = -11.5A$	
Turn-On Rise Time	t _r	_	15.4	_	ns		
Turn-Off Delay Time	t _{D(off)}	_	45.6	_	ns		
Turn-Off Fall Time	t _f		36.8	_	ns		
BODY DIODE CHARACTERISTICS							
Diode Forward Voltage	V_{SD}	_	-0.7	_	V	V _{GS} = 0V, I _S = -1A	
Reverse Recovery Time (Note 9)	t _{rr}	_	20	_	ns		
Reverse Recovery Charge (Note 9)	Qrr	_	9.5	_	nC	I _S = -11.5A, dl/dt = 100A/μs	

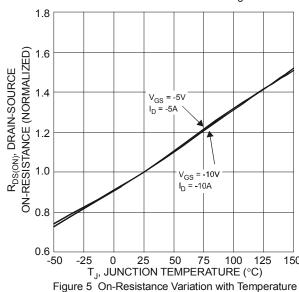
- 5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
 6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
 7. IAR and EAR rating are based on low frequency and duty cycles to keep TJ = +25°C
 8. Short duration pulse test used to minimize self-heating effect.
 9. Guaranteed by design. Not subject to product testing.











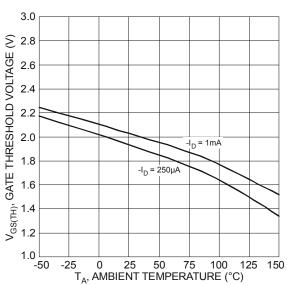
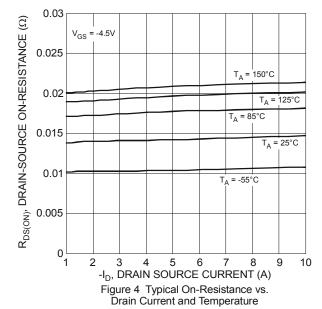
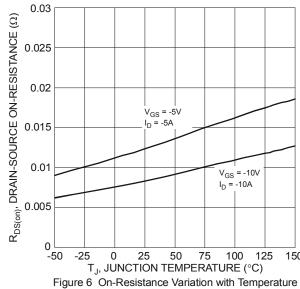
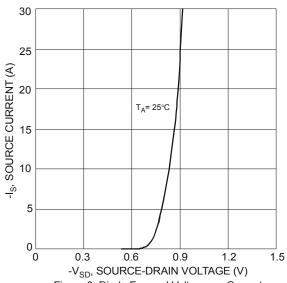


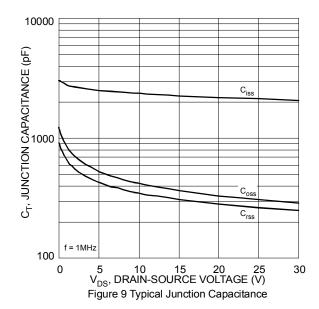
Figure 7 Gate Threshold Variation vs. Ambient Temperature

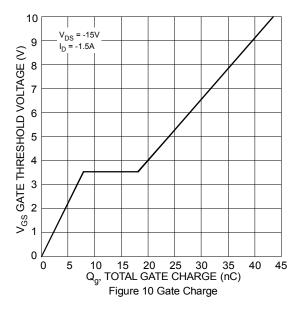


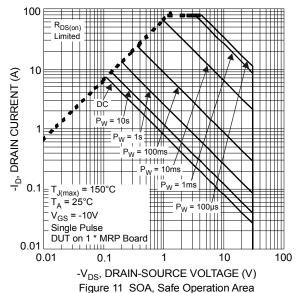


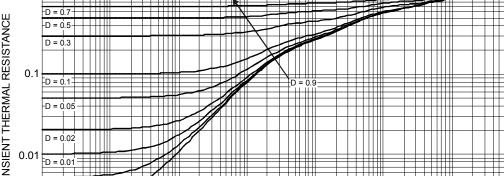










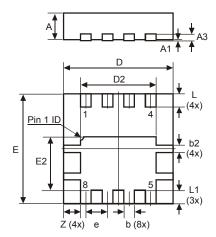


r(t), TRANSIENT THERMAL RESISTANCE D = 0.005 $R_{\theta JA}(t) = r(t) * R_{\theta JA}$ $R_{\theta JA} = 143^{\circ}C/W$ Single Pulse Duty Cycle, D = t1/t20.001 0.001 0.01 0.1 10 100 1,000



Package Outline Dimensions

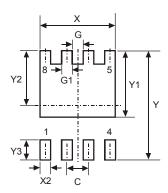
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



POWERDI3333-8					
Dim	Min	Max	Тур		
D	3.25	3.35	3.30		
Е	3.25	3.35	3.30		
D2	2.22	2.32	2.27		
E2	1.56	1.66	1.61		
Α	0.75	0.85	0.80		
A1	0	0.05	0.02		
A3	_	_	0.203		
b	0.27	0.37	0.32		
b2	_	_	0.20		
L	0.35	0.45	0.40		
L1	_	_	0.39		
е	_	_	0.65		
Z	_	_	0.515		
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	0.650
G	0.230
G1	0.420
Υ	3.700
Y1	2.250
Y2	1.850
Y3	0.700
Х	2.370
X2	0.420



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